

Surface Mount Optically Coupled Isolator

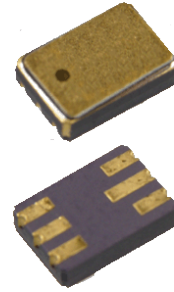
JANTX4N49U / JANTXV4N49U



Obsolete (JAN/JANTX/JANTXV 4N47U, 4N48U, JAN4N49U)

Features:

- Surface Mount (SM), Leadless Chip Carrier (LCC)
- 1 kV electrical isolation
- Base contact provided for conventional transistor biasing
- JANTX and JANTXV devices are processed to MIL-PRF-19500



Description:

Each isolator in this series consists of an infrared emitting diode and a NPN silicon phototransistor, which are mounted in a hermetically sealed Surface Mount, 6 Pin package. Devices are designed for military and/or harsh environments.

The JAN / JANTX / JANTXV 4N47U, 4N48U and 4N49U devices are processed to MIL-PRF-19500/548.

This series of 4N products are JEDEC registered, DSCC qualified.

Please contact your local representative for more information.

Applications:

- Military equipment
- High-Reliability environments
- High voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment

Ordering Information				
Part Number	Isolation Voltage (kV)	I _F (mA) Typ / Max	V _{CE} (Volts) Max	Processing MIL-PRF-19500
JAN4N47U (Obsolete)	1	1 / 40	40	548
JANTX4N47U (Obsolete)				
JANTXV4N47U (Obsolete)				
JAN4N48U (Obsolete)				
JANTX4N48U (Obsolete)				
JANTXV4N48U (Obsolete)				
JAN4N49U (Obsolete)				
JANTX4N49U				
JANTXV4N49U				

General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

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Electrical Specifications

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Storage Temperature Range	-55° C to +150° C
Operating Temperature Range	-55° C to +125° C
Input-to-Output Isolation Voltage	$\pm 1.00\text{ kVDC}^{(1)}$
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C ⁽²⁾

Input Diode

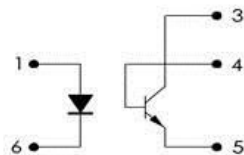
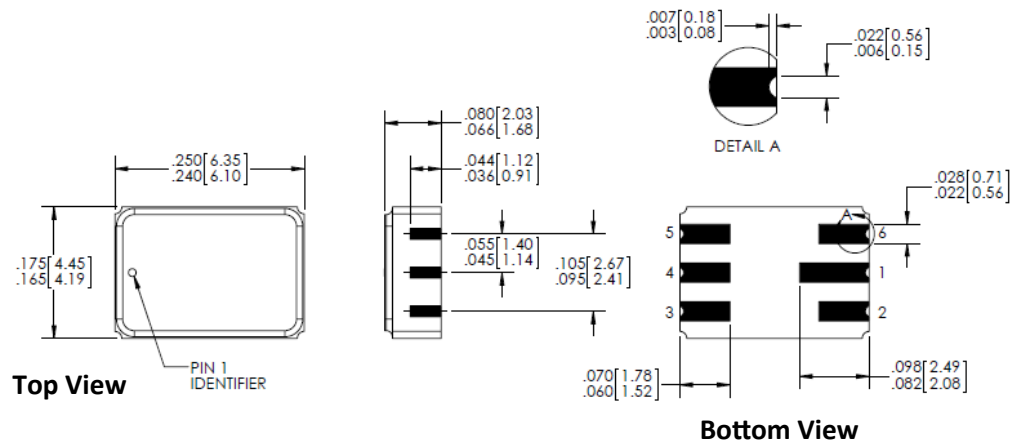
Forward DC Current (65° C or below)	40 mA
Reverse Voltage	2 V
Power Dissipation	60 mW ⁽³⁾

Output Phototransistor:

Continuous Collector Current	50 mA
Collector-Emitter Voltage	40 V
Collector-Base Voltage	45 V
Emitter-Base Voltage	7.0 V
Power Dissipation	300 mW ⁽⁴⁾

Notes:

1. Measured with input leads shorted together and output leads shorted together.
2. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
3. Derate linearly 1.0 mW/° C above 65° C.
4. Derate linearly 3.0 mW/° C above 25° C.



DIMENSIONS ARE IN INCHES [MM]

Pin #	LED	Pin #	Transistor
3	Collector	2	N/A
4	Base	1	Anode
5	Emitter	6	Cathode

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Electrical Characteristics ($T_A = 25^\circ\text{C}$ unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
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Input Diode

V_F	Forward Voltage	0.80 1.00 0.70	- - -	1.50 1.70 1.30	V	$I_F = 10.0\text{ mA}$ $I_F = 10.0\text{ mA}, T_A = -55^\circ\text{C}^{(1)}$ $I_F = 10.0\text{ mA}, T_A = 100^\circ\text{C}^{(1)}$
I_R	Reverse Current	-	-	100	μA	$V_R = 2.0\text{ V}$

Output Phototransistor

$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	40	-	-	V	$I_C = 1.0\text{ mA}, I_B = 0, I_F = 0$
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	45	-	-	V	$I_C = 100\ \mu\text{A}, I_B = 0, I_F = 0$
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	7	-	-	V	$I_E = 100\ \mu\text{A}, I_C = 0, I_F = 0$
$I_{C(OFF)}^1$	Collector-Emitter Dark Current	-	-	100	nA	$V_{CE} = 20\text{ V}, I_B = 0, I_F = 0$
$I_{C(OFF)}^2$	Collector-Emitter Dark Current	-	-	100	μA	$V_{CE} = 20\text{ V}, I_B = 0, I_F = 0, T_A = 100^\circ\text{C}^{(1)}$
$I_{CB(OFF)}$	Collector-Base Dark Current	-	-	10	nA	$V_{CB} = 20\text{ V}, I_E = 0, I_F = 0$

Coupled

$I_{C(ON)}$	On-State Collector Current JAN / JANTX / JANTXV 4N47 [U]	0.50 0.70 0.50	- - -	- - -	mA	$I_F = 1.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
	JAN / JANTX / JANTXV 4N48 [U]	1.00 1.40 1.00	- - -	5 - -		$I_F = 1.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
	JAN / JANTX / JANTXV 4N49 [U]	2.00 2.80 2.00	- - -	10 - -		$I_F = 1.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = -55^\circ\text{C}^{(1)}$ $I_F = 2.0\text{ mA}, V_{CE} = 5.0\text{ V}, I_B = 0, T_A = 100^\circ\text{C}^{(1)}$
$I_{CB(ON)}$	On-State Collector Base	30	-	-	μA	$V_{CB} = 5\text{ V}, I_E = 0, I_F = 10\text{ mA}$
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage JAN / JANTX / JANTXV 4N47 [U]	-	-	0.30	V	$I_F = 2.0\text{ mA}, I_C = 0.5\text{ mA}, I_B = 0$
	JAN / JANTX / JANTXV 4N48 [U]	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 1.0\text{ mA}, I_B = 0$
	JAN / JANTX / JANTXV 4N49 [U]	-	-	0.30		$I_F = 2.0\text{ mA}, I_C = 2.0\text{ mA}, I_B = 0$
H_{FE}	DC Current Gain	100	-	-	V	$V_{CE} = 5.0\text{ V}, I_C = 10.0\text{ mA}, I_F = 0\text{ mA}$
R_{IO}	Resistance (Input-to-Output)	10^{11}	-	-	Ω	$V_{I-O} = \pm 1000\text{ VDC}^{(3)}$
C_{IO}	Capacitance (Input-to-Output)	-	-	5	pF	$V_{I-O} = 0\text{ V}, f = 1.0\text{ MHz}^{(3)}$
t_r, t_f	Rise and Fall Time	-	-	20	μs	$V_{CC} = 10.0\text{ V}, I_F = 5.0\text{ mA}, R_L = 100\ \Omega$

Notes:

1. Guaranteed but not tested.
2. Sample tested, LTPD = 10.
3. Measured with input leads shorted together and output leads shorted together.

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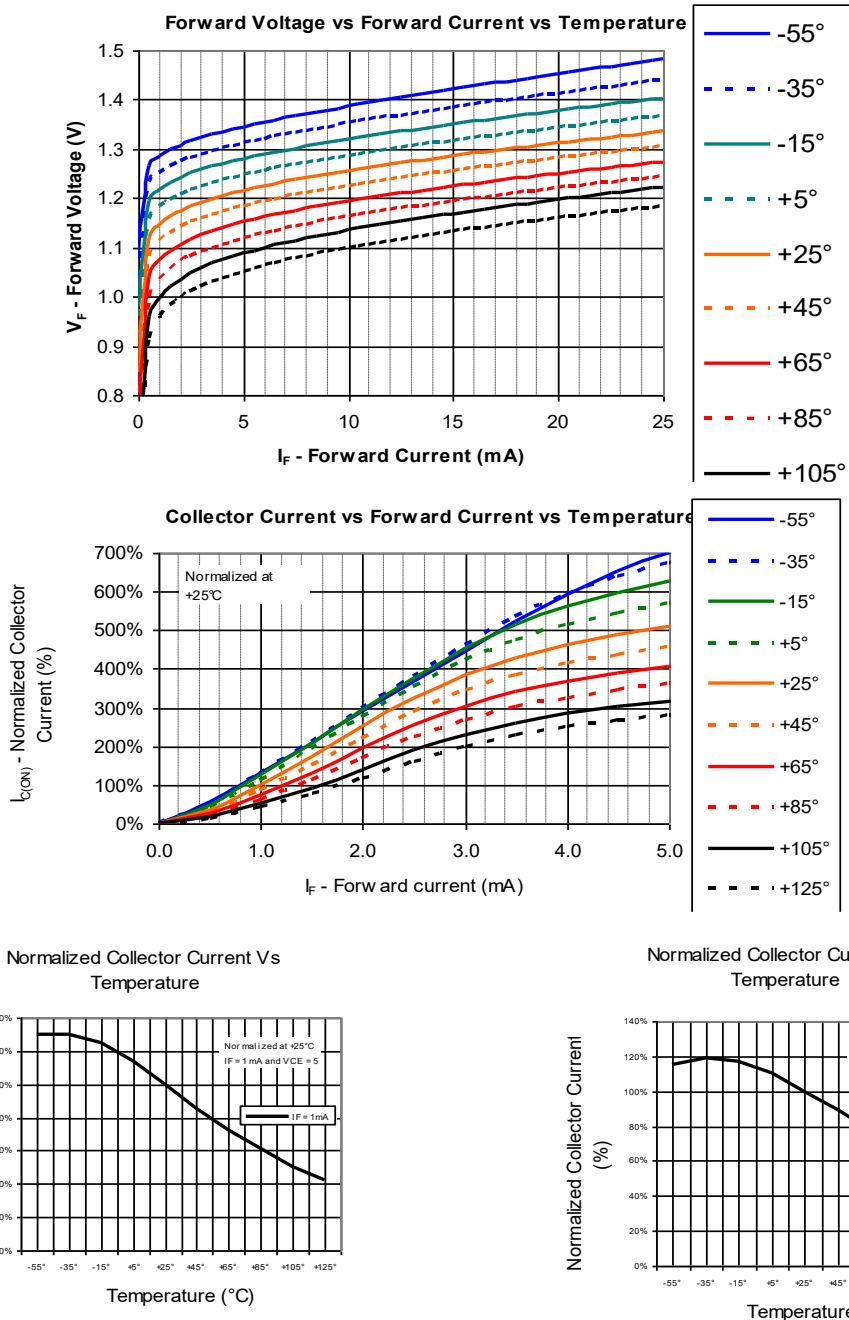
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Typical Performance Curves



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